

SAMTM Data Sheet SAM-1064-4-10ps-x, λ = 1064 nm

Laser wavelength $\lambda = 1064 \text{ nm}$

High reflection band $\lambda = 1020 ... 1100 \text{ nm}$

Absorbance $A_0 = 4 \%$ Modulation depth $\Delta R = 3 \%$ Non-saturable loss $A_{ns} = 1 \%$

Saturation fluence $\Phi_{\text{sat}} = 70 \,\mu\text{J/cm}^2$

Relaxation time constant $\tau = 10 \text{ ps}$

Damage threshold $\Phi = 2 \text{ mJ/cm}^2$

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option \mathbf{x} denotes the type of mounting as follows:

x = 0
x = 12.7 g
x = 25.4 g
x = 12.7 s
x = 12.7 s
x = 12.7 s
x = 12.7 s
x = 25.4 s
x = 25.4 s
x = 25.4 s
x = 25.0 w
x

Low intensity spectral reflectance

